Zener Voltage Regulators

500 mW SOD-123 Surface Mount

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD-123 package. These devices provide a convenient alternative to the leadless 34-package style.

Specification Features

- 500 mW Rating on FR-4 or FR-5 Board
- Wide Zener Reverse Voltage Range 2.4 V to 56 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- Peak Power 225 W (8 X 20 μs)
- AEC-Q101 Qualified and PPAP Capable
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- Pb-Free Packages are Available*

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Power Dissipation @ 20 μs (Note 1) @ T _L ≤ 25°C	P _{pk}	225	W
Total Power Dissipation on FR-5 Board, (Note 2) @ T _L = 75°C Derated above 75°C	P _D	500 6.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{\theta JA}$	340	°C/W
Thermal Resistance, Junction-to-Lead (Note 3)	$R_{ heta JL}$	150	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Nonrepetitive current pulse per Figure 11
- 2. FR-5 = 3.5 X 1.5 inches, using the ON minimum recommended footprint
- 3. Thermal Resistance measurement obtained via infrared Scan Method

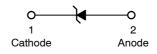


ON Semiconductor®

http://onsemi.com



SOD-123 CASE 425 STYLE 1



MARKING DIAGRAM



xxx = Device Code

M = Date Code

Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMSZxxxET1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SZMMSZxxxET1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
MMSZxxxET3G	SOD-123 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

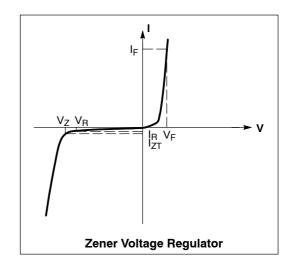
DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, $V_F = 0.95 \text{ V Max.} @ I_F = 10 \text{ mA})$

	- 1 ,
Symbol	Parameter
Vz	Reverse Zener Voltage @ I _{ZT}
I _{ZT}	Reverse Current
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _R	Reverse Leakage Current @ V _R
V _R	Reverse Voltage
I _F	Forward Current
V _F	Forward Voltage @ I _F



ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 0.9 \text{ V Max.}$ @ $I_F = 10 \text{ mA}$)

		V _{Z1} (V) (Notes 4 and 5)		Z _{ZT1} (Note 6)	V _{Z2} (Notes 4		Z _{ZT2} (Note 6)	Max Ro Leakage	everse Current	
	Device	@ I _{ZT1} = 5 mA				@ I _{ZT2} = 1 mA			I _R @ V _R	
Device*	Marking	Min	Nom	Max	Ω	Min	Max	Ω	μΑ	V
MMSZ2V4ET1G	CL1	2.28	2.4	2.52	100	1.7	2.1	600	50	1
MMSZ2V7ET1G	CL2	2.57	2.7	2.84	100	1.9	2.4	600	20	1
MMSZ3V0ET1G	CL3	2.85	3.0	3.15	95	2.1	2.7	600	10	1
MMSZ3V3ET1G	CL4	3.14	3.3	3.47	95	2.3	2.9	600	5	1
MMSZ3V6ET1G	CL5	3.42	3.6	3.78	90	2.7	3.3	600	5	1
MMSZ3V9ET1G	CL6	3.71	3.9	4.10	90	2.9	3.5	600	3	1
MMSZ4V3ET1G	CL7	4.09	4.3	4.52	90	3.3	4.0	600	3	1
MMSZ4V7ET1G	CL8	4.47	4.7	4.94	80	3.7	4.7	500	3	2
MMSZ5V1ET1G	CL9	4.85	5.1	5.36	60	4.2	5.3	480	2	2
MMSZ5V6ET1G	CM1	5.32	5.6	5.88	40	4.8	6.0	400	1	2
MMSZ6V2ET1G	CM2	5.89	6.2	6.51	10	5.6	6.6	150	3	4
MMSZ6V8ET1G	CM3	6.46	6.8	7.14	15	6.3	7.2	80	2	4
MMSZ7V5ET1G	CM4	7.13	7.5	7.88	15	6.9	7.9	80	1	5
MMSZ8V2ET1G	CM5	7.79	8.2	8.61	15	7.6	8.7	80	0.7	5
MMSZ9V1ET1G	CM6	8.65	9.1	9.56	15	8.4	9.6	100	0.5	6
MMSZ10ET1G	CM7	9.50	10	10.50	20	9.3	10.6	150	0.2	7
MMSZ11ET1G	CM8	10.45	11	11.55	20	10.2	11.6	150	0.1	8
MMSZ12ET1G	CM9	11.40	12	12.60	25	11.2	12.7	150	0.1	8
MMSZ13ET1G	CN1	12.35	13	13.65	30	12.3	14.0	170	0.1	8
MMSZ15ET1G	CN2	14.25	15	15.75	30	13.7	15.5	200	0.05	10.5
MMSZ16ET1G	CN3	15.20	16	16.80	40	15.2	17.0	200	0.05	11.2
MMSZ18ET1G	CN4	17.10	18	18.90	45	16.7	19.0	225	0.05	12.6
MMSZ20ET1G	CN5	19.00	20	21.00	55	18.7	21.1	225	0.05	14
MMSZ22ET1G	CN6	20.90	22	23.10	55	20.7	23.2	250	0.05	15.4
MMSZ24ET1G	CN7	22.80	24	25.20	70	22.7	25.5	250	0.05	16.8

Devices listed in bold, italic are ON Semiconductor Preferred devices. Preferred devices are recommended choices for future use and best overall value.

The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
 Tolerance and Voltage Designation: Zener Voltage (VZ) is measured with the Zener Current applied for PW = 1 ms.

^{6.} Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(DC)}$, with the AC frequency = 1 kHz.

^{*}Include SZ-prefix devices where applicable.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 0.9$ V Max. @ $I_F = 10$ mA)

		V _{Z1} (V) (Notes 7 and 8)			Z _{ZT1} (Note 9)	V _{Z2} (Notes 7	` '	Z_{ZT2} (Note 9)	Max Ro Leakage	
	Device		@ I _{ZT1} = 2 mA			@ I _{ZT2} =	0.1 mA	@ I _{ZT2} = 0.5 mA	I _R @	V _R
Device*	Marking	Min	Nom	Max	Ω	Min	Max	Ω	μА	V
MMSZ27ET1G	CN8	25.65	27	28.35	80	25	28.9	300	0.05	18.9
MMSZ30ET1G	CN9	28.50	30	31.50	80	27.8	32	300	0.05	21
MMSZ33ET1G	CP1	31.35	33	34.65	80	30.8	35	325	0.05	23.1
MMSZ36ET1G	CP2	34.20	36	37.80	90	33.8	38	350	0.05	25.2
MMSZ39ET1G	СРЗ	37.05	39	40.95	130	36.7	41	350	0.05	27.3
MMSZ43ET1G	CP4	40.85	43	45.15	150	39.7	46	375	0.05	30.1
MMSZ47ET1G	CP5	44.65	47	49.35	170	43.7	50	375	0.05	32.9
MMSZ51ET1G	CP6	48.45	51	53.55	180	47.6	54	400	0.05	35.7
MMSZ56ET1G	CP7	53.20	56	58.80	200	51.5	60	425	0.05	39.2

^{7.} The type numbers shown have a standard tolerance of $\pm 5\%$ on the nominal Zener Voltage.

Devices listed in bold, italic are ON Semiconductor Preferred devices. Preferred devices are recommended choices for future use and best overall value.

Tolerance and Voltage Designation: Zener Voltage (VZ) is measured with the Zener Current applied for PW = 1 ms.
 Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for I_{Z(AC)} = 0.1 I_{Z(DC)}, with the AC frequency = 1 kHz.

^{*}Include SZ-prefix devices where applicable.

TYPICAL CHARACTERISTICS

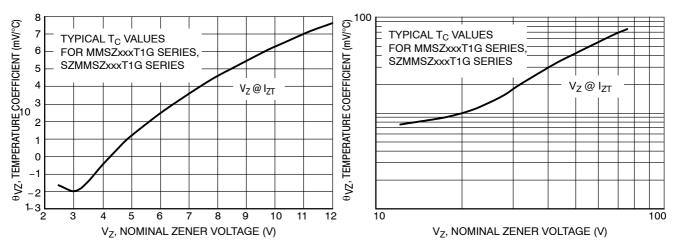


Figure 1. Temperature Coefficients (Temperature Range –55°C to +150°C)

Figure 2. Temperature Coefficients (Temperature Range –55°C to +150°C)

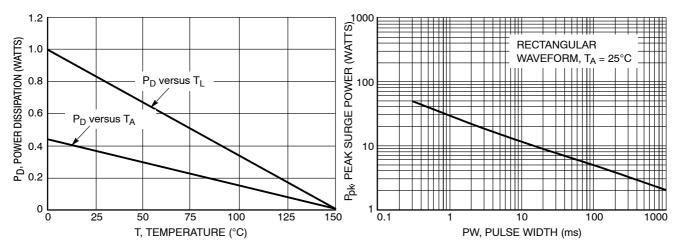


Figure 3. Steady State Power Derating

Figure 4. Maximum Nonrepetitive Surge Power

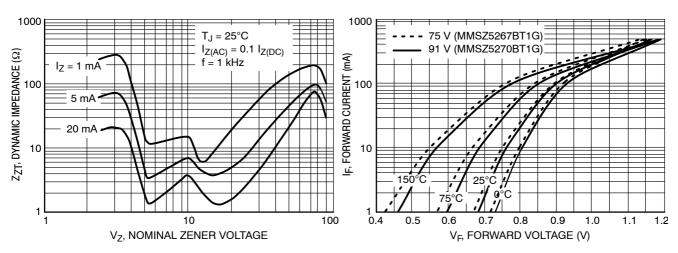


Figure 5. Effect of Zener Voltage on Zener Impedance

Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

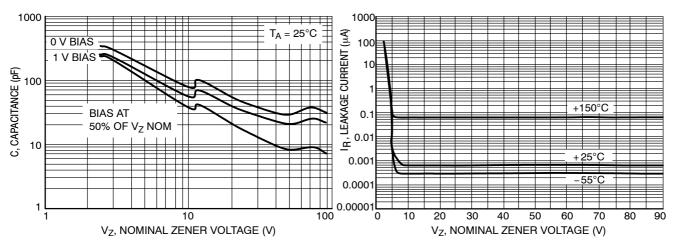


Figure 7. Typical Capacitance

Figure 8. Typical Leakage Current

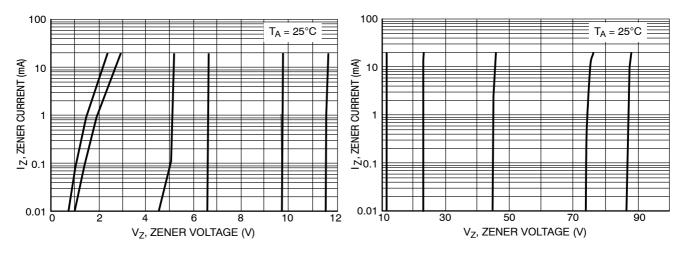


Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

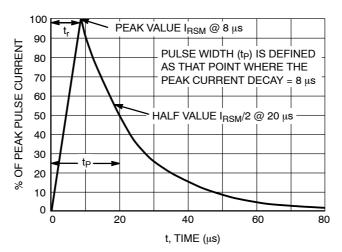


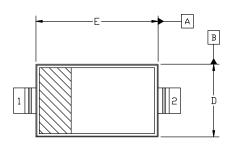
Figure 11. $8 \times 20 \mu s$ Pulse Waveform



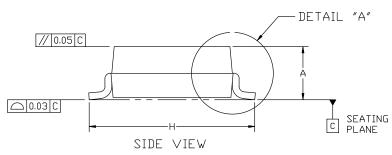


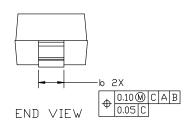
SOD-123 2-LEAD, 1.60x2.69x1.16 CASE 425 ISSUE H

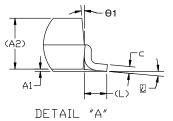
DATE 29 FEB 2024



TOP VIEW



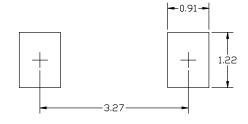




NOTES:

- . DIMENSION AND TOLERANCING PER ASME Y14.5M, 2018
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETER					
DIM	MIN.	MAX.				
А	0.94	1.17	1.35			
A1	0.00	0.05	0.10			
A2		1.16 REF.				
b	0.51	0.61	0.71			
C	_	_	0.15			
D	1.40	1.60	1.80			
Е	2.54	2.69	2.84			
Н	3.56	3.68	3,86			
L	0.25 REF.					
S	0°		10°			
θ1	0°		10°			



RECOMMENDED MOUNTING FOOTPRINT *For additional information on or Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference manual SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. CATHODE

DOCUMENT NUMBER:	98ASB42927B	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOD-123 2-LEAD, 1.60x2.69x1.16		PAGE 1 OF 1		

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

MMSZ15ET1 MMSZ15ET1G MMSZ18ET1 MMSZ18ET1G MMSZ2V4ET1G MMSZ2V7ET1G SZMMSZ2V7ET1G SZMMSZ15ET1G SZMMSZ13ET1G SZMMSZ8V2ET1G SZMMSZ18ET1G SZMMSZ33ET1G SZMMSZ33ET3G